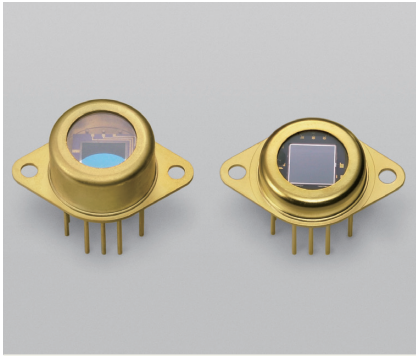


# Si photodiodes with preamp



S9295 series

## Large area photodiode integrated with op amp and TE-cooler

The S9295 series is a thermoelectrically cooled Si photodiode with preamp developed for low-light-level detection. A large area photodiode, op amp, TE-cooler and feedback resistor (10 GΩ) are integrated into a single package. A thermistor is also included in the same package for temperature control so that the photodiode and I-V conversion circuit can be cooled for stable operation. The S9295 series also features low noise and low NEP, and is especially suitable for NO<sub>x</sub> detection. The photosensitive area of the photodiode is internally connected to the GND terminal making it highly resistant to EMC noise.

### Features

- Large photosensitive area: 10 × 10 mm
- UV to NIR Si photodiode optimized for precision photometry
- Compact hermetic package with sapphire window
- High precision FET input operational amplifier
- High gain: R<sub>f</sub>=10 GΩ
- Low noise and NEP
- High cooling efficiency  
S9295 : ΔT=50 °C  
S9295-01: ΔT=30 °C
- High stability with thermistor
- Highly resistant to EMC noise

### Applications

- NO<sub>x</sub> detection
- Low-light-level measurement, etc.

The S9295 series may be damaged by Electro Static Discharge, etc. Please see Precautions in P.6.

### Absolute maximum ratings

| Parameter                                 | Symbol           | Value             |
|---|------------------|-------------------|
| Supply voltage (preamp)                   | V <sub>cc</sub>  | ±20 V             |
| Operating temperature* <sup>1</sup>       | T <sub>opr</sub> | -30 to +60 °C     |
| Storage temperature* <sup>1</sup>         | T <sub>stg</sub> | -40 to +80 °C     |
| TE-cooler allowable voltage* <sup>2</sup> | V <sub>te</sub>  | 5 V* <sup>3</sup> |
| TE-cooler allowable current               | I <sub>te</sub>  | 1 A               |
| Thermistor power dissipation              | P <sub>th</sub>  | 0.2 mW            |

\*1: No dew condensation

When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

\*2: Ripple max.: 10%

\*3: S9295-01: 3.7 V

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

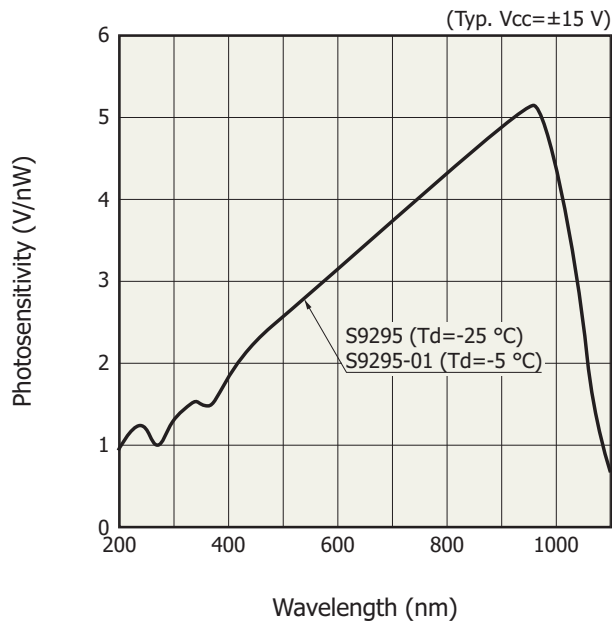
### Recommended operating conditions

| Parameter                    | Symbol          | Value        |
|------------------------------|-----------------|--------------|
| Supply voltage (preamp)      | V <sub>cc</sub> | ±5 to ±15 V  |
| TE-cooler current            | I <sub>te</sub> | 0.8 A max.   |
| Thermistor power dissipation | P <sub>th</sub> | 0.03 mW max. |
| Load resistance              | R <sub>L</sub>  | 100 kΩ min.  |

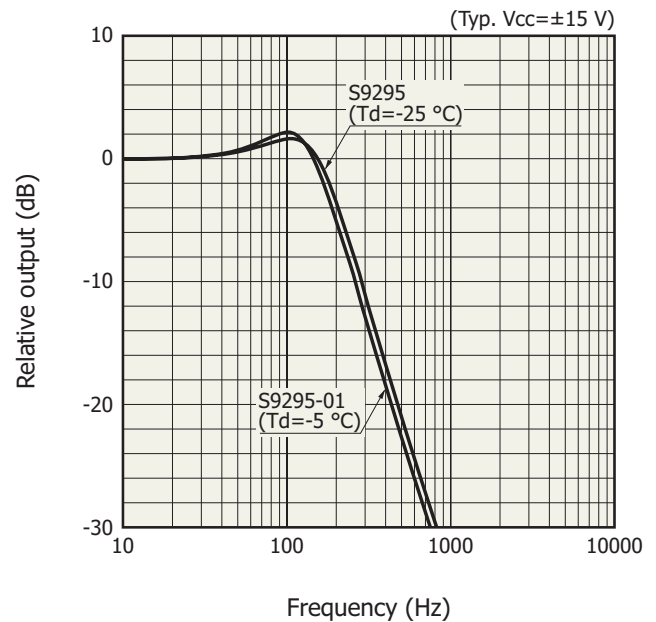
### Electrical and optical characteristics (Typ. $V_{CC} = \pm 15\text{ V}$ , $R_L = 1\text{ M}\Omega$ )

| Parameter                      | Symbol      | Condition                                  | S9295                             | S9295-01                         | Unit                              |
|--------------------------------|-------------|--|-----------------------------------|----------------------------------|-----------------------------------|
|                                |             |  | $T_d = -25\text{ }^\circ\text{C}$ | $T_d = -5\text{ }^\circ\text{C}$ |                                   |
| Spectral response range        | $\lambda$   |  | 190 to 1100                       |                                  | nm                                |
| Peak sensitivity wavelength    | $\lambda_p$ |  | 960                               |                                  | nm                                |
| Feedback resistance (built-in) | $R_f$       |  | 10                                |                                  | $\text{G}\Omega$                  |
| Photosensitivity               | S           | $\lambda = 200\text{ nm}$                  | 0.9                               |                                  | V/nW                              |
|                                |             | $\lambda = \lambda_p$                      | 5.1                               |                                  |                                   |
| Output noise voltage           | $V_n$       | Dark state, $f = 10\text{ Hz}$             | 20                                | 25                               | $\mu\text{V rms}/\text{Hz}^{1/2}$ |
| Noise equivalent power         | NEP         | $\lambda = \lambda_p$ , $f = 10\text{ Hz}$ | 4                                 | 5                                | $\text{fW}/\text{Hz}^{1/2}$       |
| Output offset voltage          | $V_{os}$    | Dark state                                 | $\pm 2$                           |                                  | mV                                |
| Cutoff frequency               | $f_c$       | -3 dB                                      | 190                               | 180                              | Hz                                |
| Output voltage swing           | $V_o$       |  | 13                                |                                  | V                                 |
| Supply current                 | $I_{cc}$    | Dark state                                 | 0.3                               |                                  | mA                                |
| Thermistor resistance          | $R_{th}$    |  | 86                                | 30                               | $\text{k}\Omega$                  |

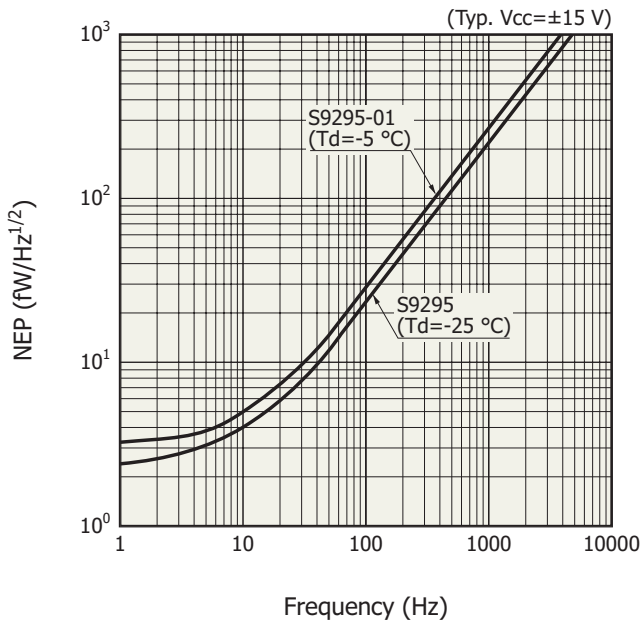
### Spectral response



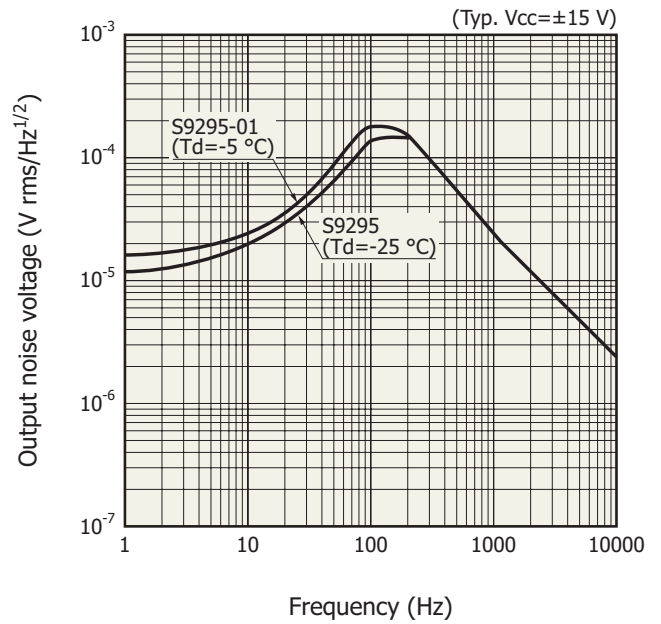
### Frequency response



NEP vs. frequency

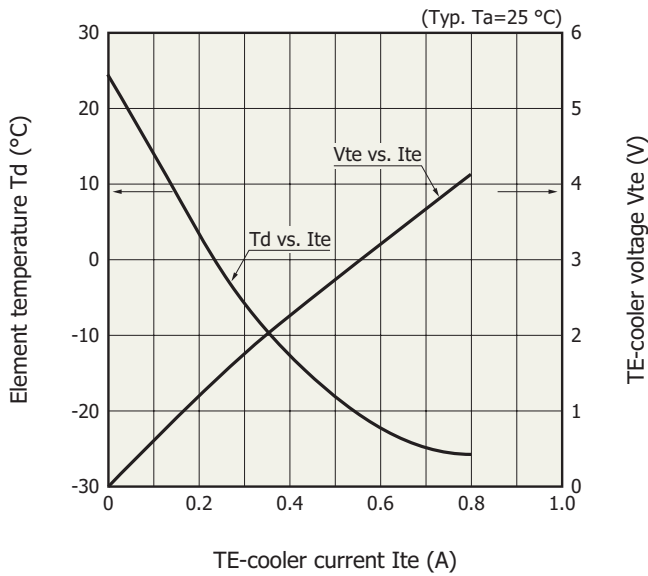


Output noise voltage vs. frequency

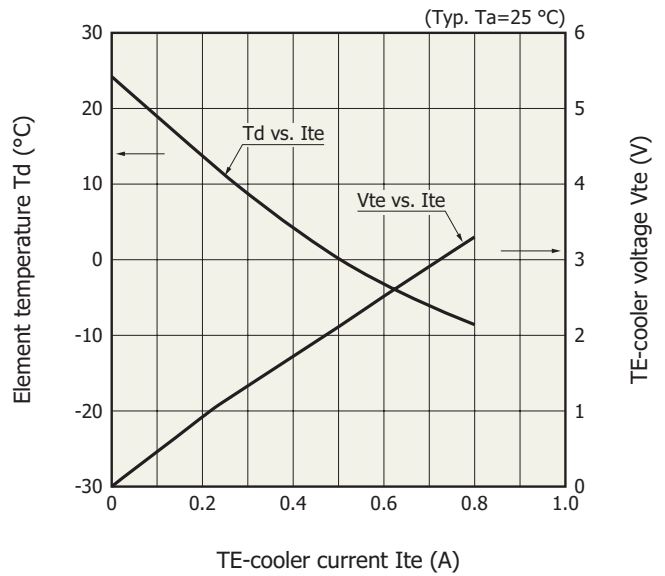


Element temperature vs. TE-cooler current

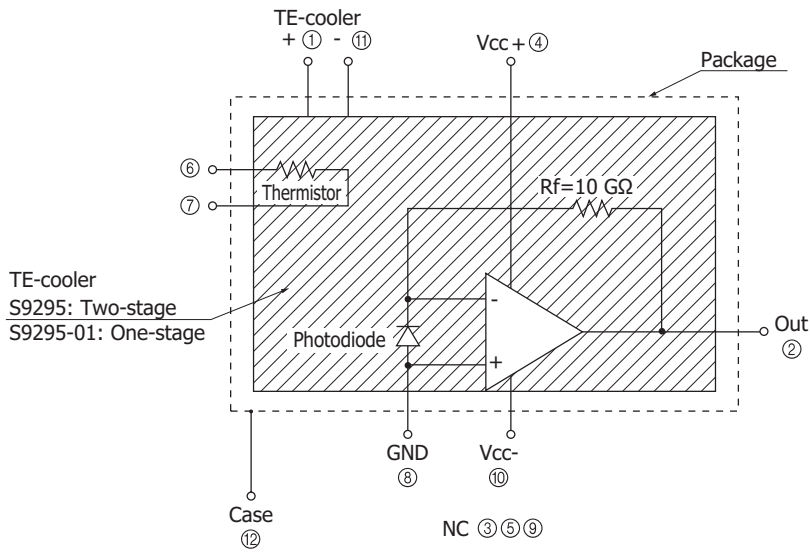
S9295



S9295-01

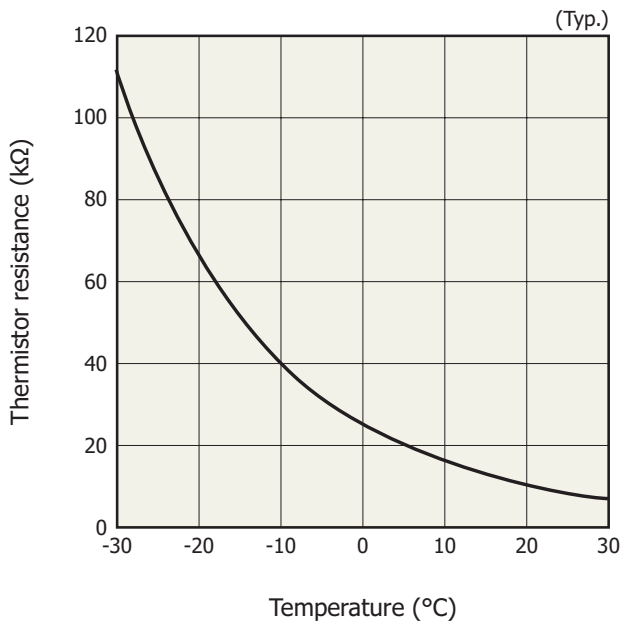


External connection



KSPDC0047EA

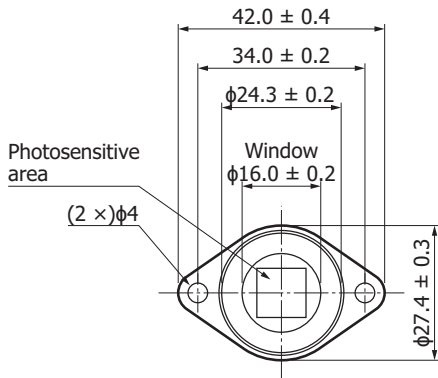
Thermistor resistance vs. temperature



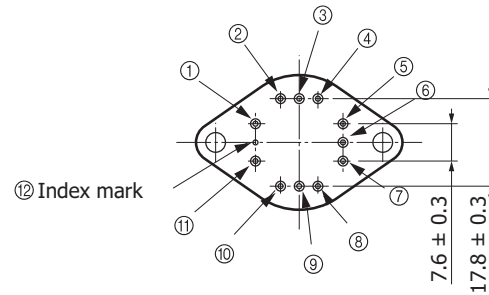
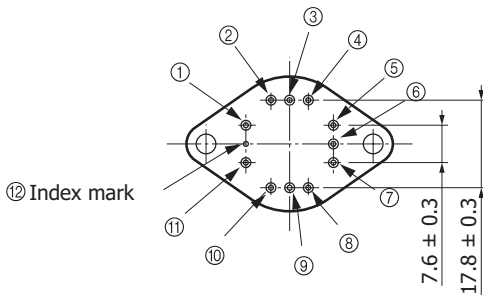
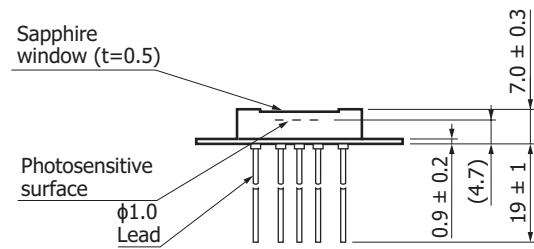
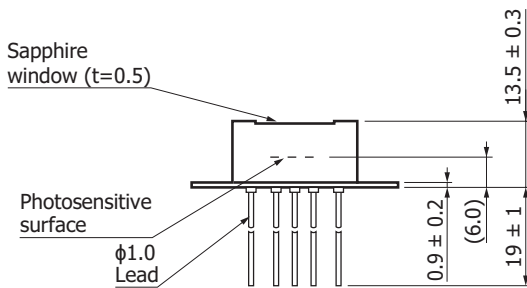
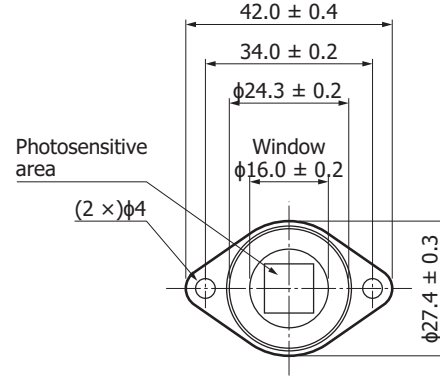
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**Dimensional outlines (unit: mm)**

S9295



S9295-01



KSPDA0071EC

KSPDA0079EB

A tantalum or ceramic capacitor of 0.1 to 10  $\mu\text{F}$  must be connected to the supply voltage leads (pins ④ and ⑩) as a bypass capacitor used to prevent the device from oscillation.

## ■ Precautions

### ■ ESD

The S9295 series may be damaged or their performance may deteriorate by such factors as electro static discharge from the human body, surge voltage from measurement equipment, leakage voltages from soldering irons and packing materials. As a countermeasure against electro static discharge, the device, operator, work place and measuring jigs must all be set at the same potential. The following precautions must be observed during use:

- To protect the device from electro static discharge which accumulate on the operator or the operator,s clothes, use a wrist strap or similar tools to ground the operator,s body via a high impedance resistor (1 MΩ).
- A semiconductive sheet (1 MΩ to 10 MΩ) should be laid on both the work table and the floor in the work area.
- When soldering, use an electrically grounded soldering iron with an isolation resistance of more than 10 MΩ.
- For containers and packing, use of a conductive material or aluminum foil is effective. When using an antistatic material, use one with a resistance of 0.1 MΩ/cm<sup>2</sup> to 1 GΩ/cm<sup>2</sup>.

### ■ Strength

- Thermoelectrically-cooler devices may be damaged if subjected to shock, for example drop impact. Take sufficient care when handling these devices.

### ■ Lead forming

- When forming the leads, take care not to apply excessive force to the lead sealing glass. Excessive force may impair the hermetic sealing, possibly degrading the cooling capacity. To form the leads, hold the roots of the leads securely with a pair of pliers and bend them.

### ■ Heatsink

- Use a heatsink with thermal resistance less than 1.3 °C/W. Apply thermal grease between the heatsink and detector package, and then fasten them with the screws. Be careful not to give any excessive force or mechanical stress to the detector package at this point.

### ■ Wiring

- Be careful not to misconnect the plus and minus leads of the thermoelectric cooler or preamplifier. Supplying a voltage or current while these connections are reversed may damage the device.
- The feedback resistor integrated into S9295 series is high so it is susceptible to external noise. Always ground the case terminal when using S9295.

### ■ Against UV light exposure

- When UV light irradiation is applied, the product characteristics may degrade. Such examples include degradation of the product's UV sensitivity and increase in dark current. This phenomenon varies depending on the irradiation level, irradiation intensity, usage time, and ambient environment and also varies depending on the product model. Before employing the product, we recommend that you check the tolerance under the ultraviolet light environment that the product will be used in.
- Exposure to UV light may cause the characteristics to degrade due to gas released from the resin bonding the product's component materials. As such, we recommend that you avoid applying UV light directly on the resin and apply it on only the inside of the photosensitive area by using an aperture or the like.

## Related information

[www.hamamatsu.com/sp/ssd/doc\\_en.html](http://www.hamamatsu.com/sp/ssd/doc_en.html)

### ■ Precautions

- Disclaimer
- Metal, ceramic, plastic package products

### ■ Technical information

- Si photodiode/Application circuit examples

Information described in this material is current as of February, 2021.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

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# HAMAMATSU

[www.hamamatsu.com](http://www.hamamatsu.com)

HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Higashi-ku, Hamamatsu City, 435-8558 Japan, Telephone: (81)53-434-3311, Fax: (81)53-434-5184

U.S.A.: Hamamatsu Corporation: 360 Foothill Road, Bridgewater, N.J. 08807, U.S.A., Telephone: (1)908-231-0960, Fax: (1)908-231-1218, E-mail: [usa@hamamatsu.com](mailto:usa@hamamatsu.com)

Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49)8152-375-0, Fax: (49)8152-265-8, E-mail: [info@hamamatsu.de](mailto:info@hamamatsu.de)

France: Hamamatsu Photonics France S.A.R.L.: 19, Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: (33)1 69 53 71 00, Fax: (33)1 69 53 71 10, E-mail: [infos@hamamatsu.fr](mailto:infos@hamamatsu.fr)

United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire AL7 1BW, UK, Telephone: (44)1707-294888, Fax: (44)1707-325777, E-mail: [info@hamamatsu.co.uk](mailto:info@hamamatsu.co.uk)

North Europe: Hamamatsu Photonics Norden AB: Torshamnsgatan 35 16440 Kista, Sweden, Telephone: (46)8-509 031 00, Fax: (46)8-509 031 01, E-mail: [info@hamamatsu.se](mailto:info@hamamatsu.se)

Italy: Hamamatsu Photonics Italia S.r.l.: Strada della Moia, 1 inf. 6, 20020 Arese (Milano), Italy, Telephone: (39)02-93 58 17 33, Fax: (39)02-93 58 17 41, E-mail: [info@hamamatsu.it](mailto:info@hamamatsu.it)

China: Hamamatsu Photonics (China) Co., Ltd.: 1201 Tower B, Jiaming Center, 27 Dongsanhuan Beilu, Chaoyang District, 100020 Beijing, P.R.China, Telephone: (86)10-6586-6006, Fax: (86)10-6586-2866, E-mail: [hpc@hamamatsu.com.cn](mailto:hpc@hamamatsu.com.cn)

Taiwan: Hamamatsu Photonics Taiwan Co., Ltd.: 8F-3, No. 158, Section2, Gongdao 5th Road, East District, Hsinchu, 300, Taiwan R.O.C. Telephone: (886)3-659-0080, Fax: (886)3-659-0081, E-mail: [info@hamamatsu.com.tw](mailto:info@hamamatsu.com.tw)